

2SD1838

# **Driver Applications**

## **Applications**

· Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers).

### **Features**

- · High DC current gain.
- · Large current capacity
- · Wide ASO.
- On-chip Zener diode of 60±10V between collector and base.
- · Uniformity in collector-to-base breakdown voltage due to adoption of accurate impurity diffusion process.
- · High inductive load handling capability.
- · Micaless package facilitating mounting.

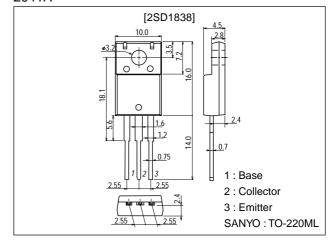
## **Specifications**

## Absolute Maximum Ratings at Ta = 25°C

## **Package Dimensions**

unit:mm

2041A



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		50*	V
Collector-to-Emitter Voltage	VCEO		50*	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	Ic		5	Α
Collector Current (Pulse)	I <sub>CP</sub>		8	Α
Base Current	ΙB		0.5	Α
Collector Dissipation	PC		2.0	W
	L.C.	Tc=25°C	25	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

<sup>\*:</sup> With Zener diode of (60±10V).

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =40V, I <sub>E</sub> =0			100	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0			3	mA
DC Current Gain	hFE	V <sub>CE</sub> =3V, I <sub>C</sub> =2.5A	1000	4000		
Gain-Bandwidth Product	fT	V <sub>CE</sub> =5V, I <sub>C</sub> =2.5A		20		MHz
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =2.5A, I <sub>B</sub> =5mA		0.9	1.5	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =2.5A, I <sub>B</sub> =5mA			2.0	V

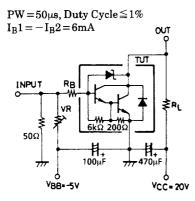
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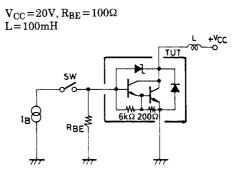
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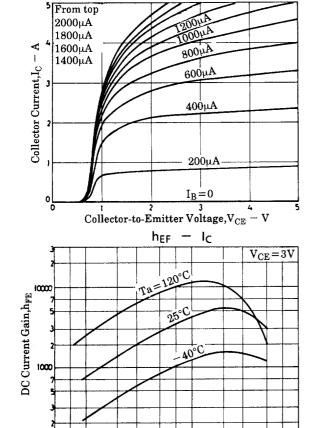
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =5mA, I <sub>E</sub> =0	50	60	70	V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =50mA, R <sub>BE</sub> =∞	50	60	70	V
Inductive Load Handling Capability	Es/b	L=100mH, $R_{BE}$ =100 $\Omega$	50			mJ
Rise Time	ton	See specified Test Circuit. V <sub>CC</sub> =20V, I <sub>C</sub> =3.0A, I <sub>B1</sub> =-I <sub>B2</sub> =6mA		0.6		μs
Storage Time	t <sub>stg</sub>	See specified Test Circuit.  V <sub>CC</sub> =20V, I <sub>C</sub> =3.0A, I <sub>B1</sub> =-I <sub>B2</sub> =6mA		4.0		μs
Fall Time	t <sub>f</sub>	See specified Test Circuit.  V <sub>CC</sub> =20V, I <sub>C</sub> =3.0A, I <sub>B1</sub> =-I <sub>B2</sub> =6mA		1.5		μs

## **Specified Test Circuit**



## Es/b Test Circuit

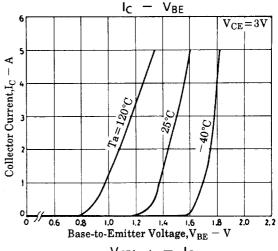


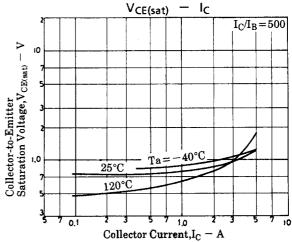


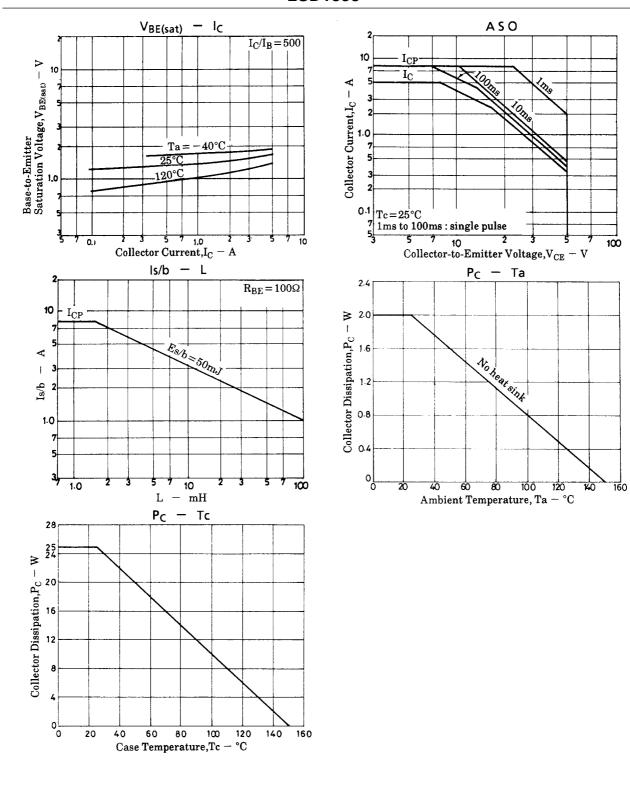
1.0

Collector Current,  $I_C - A$ 

IC - VCE







### 2SD1838

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